Photo Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-489-6782

# Inclosure Material:

Metal

**Overall Length:** 

0.210 inches

# **Terminal Length:**

0.400 inches

# **Overall Diameter:**

0.210 inches

# Internal Configuration:

Junction contact

## Mounting Method:

Terminal

## **Terminal Circle Diameter:**

0.100 inches

## Features Provided:

## Hermetically sealed case

Semiconductor Material:

Silicon

# Voltage Rating In Volts Per Characteristic:

80.0 collector to base voltage/static/emitter open and 30.0 collector to emitter voltage/static/base open and 5.0 emitter to base voltage, static, collector open

Power Rating Per Characteristic:

200.0 milliwatts small-signal input power, common-collector preset

# Maximum Operating Tempurature Per Measurement Point:

85.0 degrees celsius ambient air

#### **Special Features:**

Junction pattern arrangement: npn

## **Terminal Type And Quantity:**

3 uninsulated wire lead

## Shelf Life:

N/a

#### Unit Of Measure:

--

#### **Demilitarization:**

Yes - demil/mli

Fiig:

A110a0